NSN 5961-01-461-7964

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Mounting Method:
Unthreaded hole
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
200.0 breakdown voltage, collector-to-emitter, base open
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0